



Our paper "[Carrier lifetime in erbium-doped GaN waveguide emitting in 1540nm wavelength](#)" is one of *Applied Physics Letters'* most downloaded articles of the last five years. [*2011 Journal Citation Reports*® (Thomson Reuters, 2012)].

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**Date:** August 8, 2012 11:22:41 AM PDT  
**To:** <[jingyu.lin@TTU.EDU](mailto:jingyu.lin@TTU.EDU)>  
**Subject:** **APL: Carrier lifetime in erbium-doped GaN waveguide emitting in 1540nm wavelength**  
**Reply-To:** <[journals@aip.org](mailto:journals@aip.org)>

Dear Prof. Dr. Jingyu Lin,

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